

3.3 GHz to 6.2 GHz GENERAL PURPOSE 3.3 V 15 dBm AMPLIFIER

Package: S0T-363, 2.0 mm x 2.1 mm



Product Description

RFMD's STA-5063Z is a general purpose class A linear amplifier which utilizes InGaP GaAs Heterojunction Bipolar Transistor (HBT) amplifier housed in a low-cost surface- mountable plastic package. This product is specifically designed as a driver amplifier for WLAN 802.11a and 5.8GHz ISM band and 3.3GHz to 3.8GHz fixed wireless applications. It can run from a fixed 3.0V to 3.6V supply with its on chip active bias network which includes a power up and down control. On-chip impedance matching circuitry provides a 50Ω nominal RF input and output impedance. Its high linearity makes it an ideal choice for multicarrier and digital applica-

Optimum Technology
Matching® Applied

GaAS HBT

GaAS MESFET

✓ InGaP HBT

SiGe BiCMOS

Si BiCMOS

SiGe HBT

GaAS pHEMT

Si CMOS

Si BJT

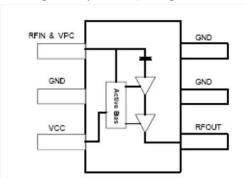
GaN HEMT

InP HBT

BIFET HBT

LDMOS

tions. Housed in an industry standard SOT-363 package, it has no blind solder joints and designed for low cost. This product is offered in a RoHS Compliant and Green package with matte tin finish, designated by the "Z" package suffix.



Features

- Linear Class A Performance
- P_{1dB} = 17.5 dBm at 3.5 GHz
- P_{1dB}=15dBm at 5.9GHz
- IP₃=30dBm at 3.5GHz
- $IP_3 = 27 \, dBm$ at 5.9 GHz
- Power Up/Down Control<1uS</p>
- Active Bias Controlled
- Robust Class 1C ESD Rating

Applications

- Driver Stage for 802.11a
 Access Points
- Wimax 802.16 Driver Stage
- Low Power 5.8GHz ISM Output Stage
- Fixed Wireless, UNII Driver Stage

Parameter	Specification			Unit	Condition
Farameter	Min.	Тур.	Max.	Unit	Condition
Small Signal Gain	17.5	19.0	21.0	dB	3.5 GHz with 3 GHz app circuit
	13.2	14.7	16.7	dB	5.1GHz with 5GHz app circuit
	12.5	14.0	16.0	dB	5.9GHz with 5GHz app circuit
Output Power at 1dB Compression		17.5		dBm	3.5 GHz with 3 GHz app circuit
		15.0		dBm	5.1GHz with 5GHz app circuit
	13.5	15.0		dBm	5.9GHz with 5GHz spp circuit
Output Third Order Intercept Point	28.0	30.0		dBm	3.5 GHz
	25.0	27.0		dBm	5.9GHz
Frequency of Operation	3.3		6.2	GHz	
Noise Figure		9.0	10.5	dB	5.9GHz
Input VSWR		1.5	2.0		5.1GHzto5.9GHz for 5GHz app circuit
Output VSWR		2.0	2.6		5.1GHzto 5.9GHz for 5GHz app circuit
Total Device Current	42.0	52.0	62.0	mA	
Thermal Resistance		150		°C/W	junction to backside
T + 0 111 E 1 11 B 1 7		01/ 1 50 4 7 6			1

Test Conditions: Evaluation Board, $Z_0 = 50\Omega$, $V_{CC} = 3.3 \text{ V}$, $I_Q = 52 \text{ mA}$, $T = 25 ^{\circ}\text{C}$



Absolute Maximum Ratings

•		
Parameter	Rating	Unit
Max Device Current (I _D)	80	mA
ESD Rating (HBM)	1000	V
Total Device Current (I)	80	mA
Device Voltage (Pins 1 and 3)	4	V
Device Voltage (Pin 4)	5.5	V
Max RF Input Power	15	dBm
Power Dissipation	0.40	W
Max Junction Temperature (T _J)	150	°C
Operating Temperature Range (T _L)	-40 to + 85	°C
Max Storage Temperature	-40to+150	°C

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one. Bias Conditions should also satisfy the following expression: $I_D V_D < (T_J - T_L) / R_{TH}, \ |_{I} |$



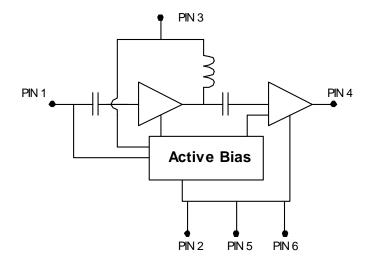
Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

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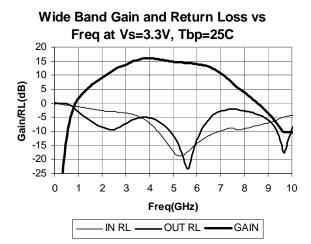
Simplified Device Schematic

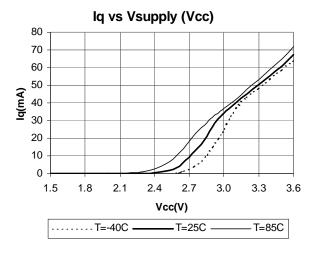


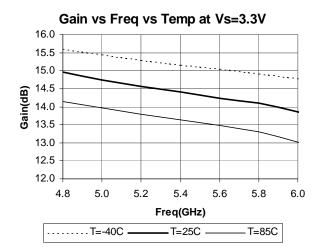


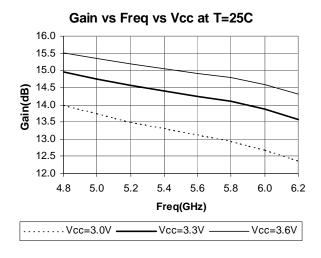
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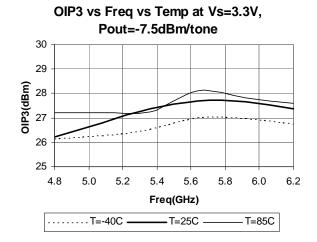
5.1 GHz to 5.9 GHz Evaluation Board Data ($V_{CC} = V_{BIAS} = 3.3 V$, $I_q = 52 \text{ mA}$)

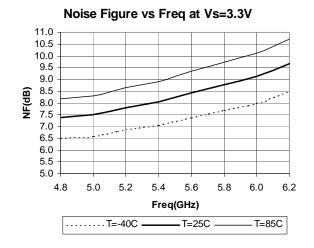






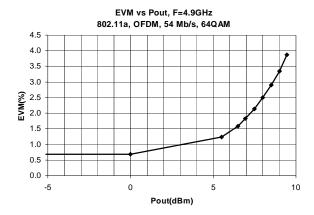


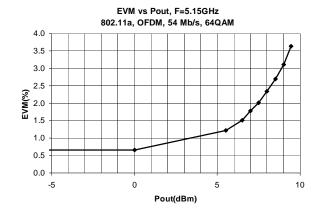


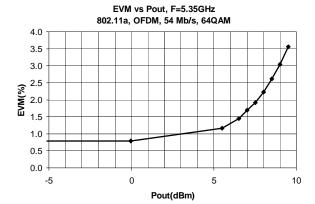


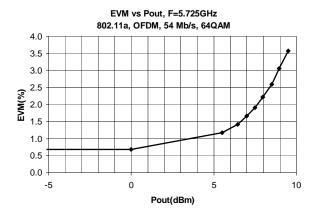


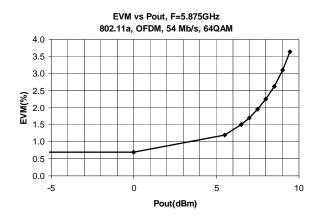
4.9 GHz to 5.9 GHz 802.11a Error Vector Magnitude Data (source EVM=0.7%)









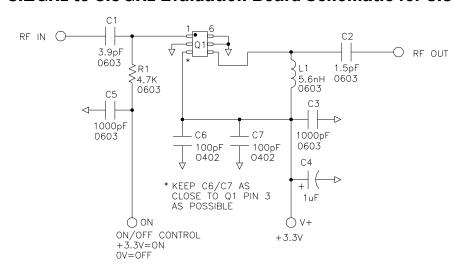




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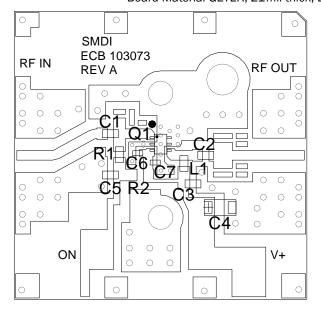
Pin	Function	Description
1	RF IN / VPC	RF input pin and power up down control. Supply VPC = 3.3V thru a 4.7 Kohm resistor to this pin. For more gain (~0.3dB), a 5.6nH inductor can also be used in place of the resistor. If an inductor is used, move the 4.7k resistor towards the DC supply, but still in series with pin 1. A minimum 1k series resitance is required on thispin from the DC supply. VPC less than 2V shuts off the amplifier.
2,5,6	GROUND	Put GND vias as close as possible to these pins. It is recommended to use the via pattern in out eval board layout and recommended land pattern
3	VCC	This provides V_{CC} to the active bias circuit and supplies the V_{CC1} collector voltage of the first stage. This pin needs to be bypassed with capacitors as close as possible to the pin. Two 0402 100 pF capacitors are recom-mended in parallel to lower the inductance to GND thru the caps.
4	RF OUT	Rf output for the amplifier and V _{CC2} for the second stage.

5.1 GHz to 5.9 GHz Evaluation Board Schematic for 3.3 V



5.1GHz to 5.9GHz Evaluation Board

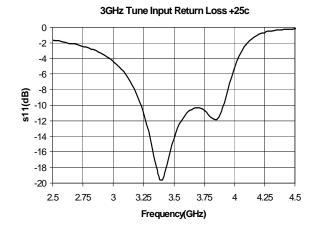
Board Material GETEK, 21mil thick, Dk=4.2, 2oz. copper.

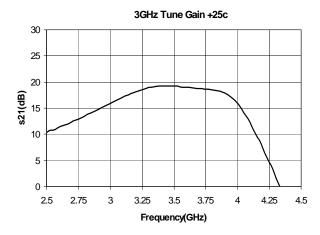


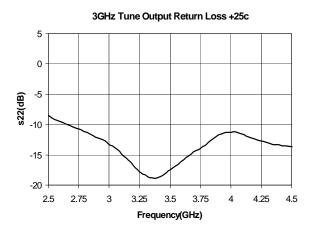
DESG	DESCRIPTION
Q1	STA-5063
R1	4.7K OHM, 0603
C1	3.9pF CAP, 0603
C2	1.5pF CAP, 0603
C3	1000pF CAP, 0603
C4	1uF 16V TANTALUM CAP
C5	1000pF CAP, 0603
C6	100pF CAP, 0402
C7	100pF CAP, 0402
L1	5.6nH INDUCTOR, 0603

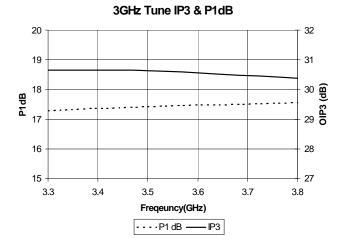


3.3 GHz to 3.8 GHz Evaluation Board Data ($V_{CC} = V_{BIAS} = 3.3 \text{V}, I_q = 52 \text{ mA}$)



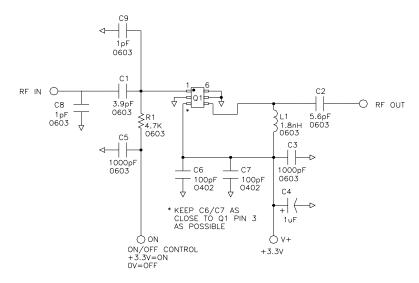






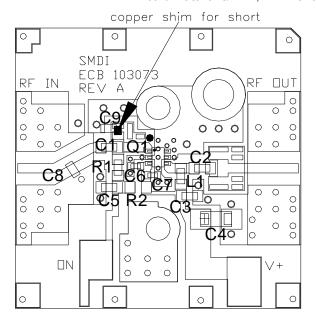


3.3 GHz to 3.8 GHz Evaluation Board Schematic for 3.3 V



3.3 GHz to 3.8 GHz Evaluation Board

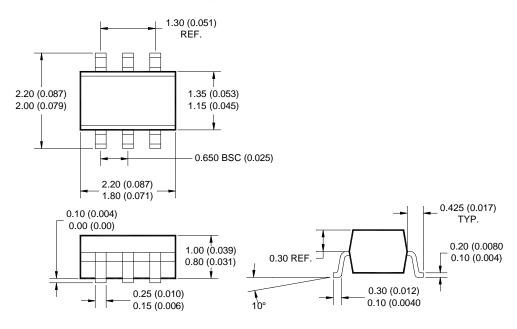
Board Material GETEK, 21mil thick, Dk=4.2, 2oz. copper.



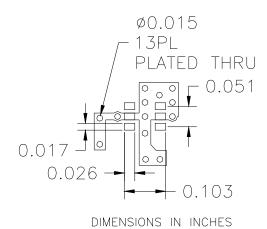
DESG	DESCRIPTION
Q1	STA-5063
R1	4.7K OHM, 0603
R2	NOT INSTALLED
C1	3.9PF, 0603
C2	5.6PF, 0603
C3	1000PF, 0603
C4	1UF, 16V
C5	1000PF, 0603
C6	100PF, 0402
C7	100PF, 0402
C8,C9	1.0pF , 0603
L1	1.8nH INDUCTOR, 0603



Package Outline Drawing

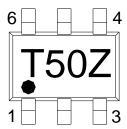


Recommended Land Pattern

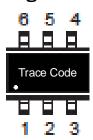




Part Identification Marking



Alternate Marking with Trace Code Only





Ordering Information

Ordering Code	Description
STA5063ZSQ	Standard 25 piece bag
STA5063ZSR	Standard 100 piece bag
STA5063Z	Standard 3000 piece reel
STA5063ZPCK-EVB1	Evaluation Board 3.3 GHz to 3.8 GHz Tune
STA5063ZPCK-EVB2	Evaluation Board 4.9GHz to 5.9GHz Tune

Mouser Electronics

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Qorvo:

STA5063Z STA5063ZSR